

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	30	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	I <sub>C</sub>	200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D	310	mW	
Power Dissipation	(Note 6)	$ P_D$	350	MIVV	
Thermal Resistance, Junction to Ambient	(Note 5)	0	403	°C/W	
	(Note 6)	$R_{ heta JA}$	357	C/VV	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{\theta JL}$	350	°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 8)

Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air

conditions whilst operating in a steady-state.

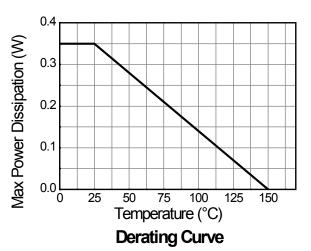
6. Same as Note 5, except the device is mounted on 15 mm x 15mm 1oz copper.

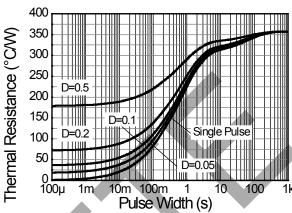
7. Thermal resistance from junction to solder-point (at the end of the leads).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

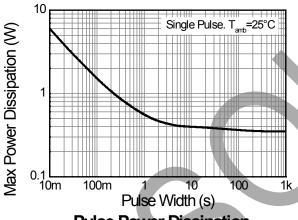


# **Thermal Characteristics and Derating Information**





Transient Thermal Impedance



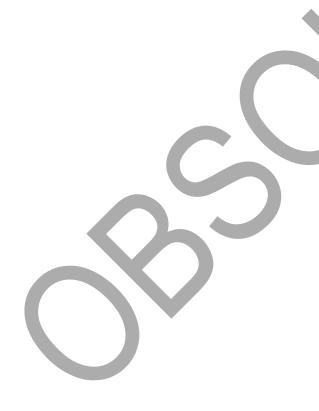
**Pulse Power Dissipation** 



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	$BV_{CBO}$	30	-	V	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 9)	$BV_CEO$	25	-	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	5.0	-	V	$I_E = 10 \mu A, I_C = 0$
Collector-Base Cut-off Current	I <sub>CBO</sub>	-	50	nA	$V_{CB}=20V, I_{E}=0$
Emitter Base Cut-off Current	I <sub>EBO</sub>	-	50	nA	$V_{EB}$ =3.0V, $I_{C}$ = 0
ON CHARACTERISTICS (Note 9)					•
DC Current Gain	$h_{FE}$	120	360		$I_{\rm C} = 2mA, V_{\rm CE} = 1.0V$
DC Current Gain	• -	60	-		$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	-	0.30	٧	$I_{\rm C} = 50  \rm mA, \ I_{\rm B} = 5.0  \rm mA$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	-	0.95	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	$C_{obo}$	-	4.0	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	$C_{ibo}$	-	8.0	pF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_{C} = 0$
Small Signal Current Gain	h <sub>fe</sub>	120	480		$V_{CE} = 1.0V, I_{C} = 2.0mA,$
Sitiali Signal Culterit Gairi	I Ife	120	400		f = 1.0kHz
Current Gain-Bandwidth Product	f⊤	300			V <sub>CE</sub> = 20V, I <sub>C</sub> = 10mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.





## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

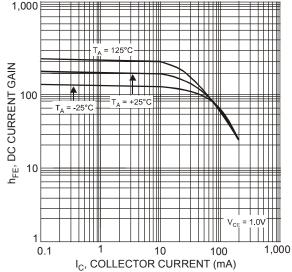
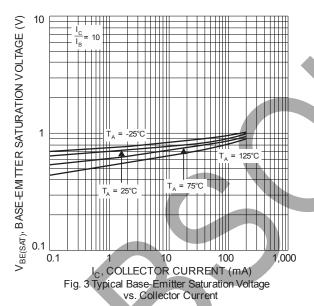


Fig. 1 Typical DC Current Gain vs. Collector Current



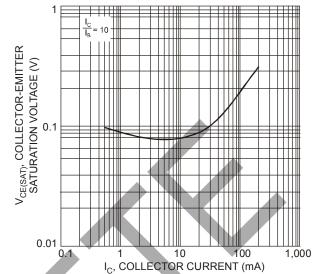


Fig. 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

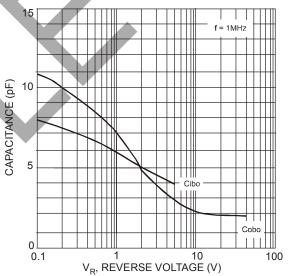
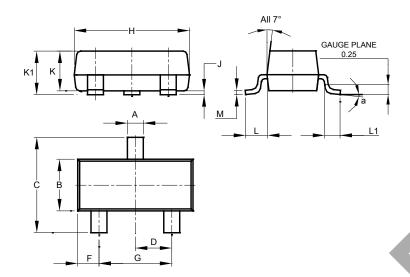


Fig. 4 Typical Capacitance Characteristics



## **Package Outline Dimensions**

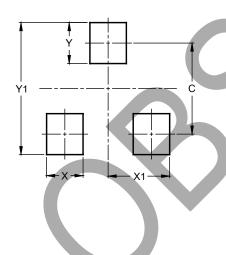
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°	-		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	29



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